## Octal Bus Transceivers With 3 State Outputs

# HITACHI

ADE-205-026 (Z) Rev.0 June 1993

#### Description

The HD74BC640A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC. When the frequency is 10 MHz. The device has eight bus transceivers with three state outputs in a 20 pin package. Each device has an active low enable input ( $\overline{G}$ ) and a direction control input, DiR. When DiR is high, data flows from the A inputs to the B outputs. When DiR is high, data flows from the B inputs to the A outputs. When enable inputs ( $\overline{G}$ ) is high, disables both A and B ports by placing then in a high impedance.

## Features

- Input/Output are at high impedance state when power supply is off.
- Input pins can be open, when not used, owing to built in input pull up circuit.
- Input is TTL level.
- Wide operating temperature range

Ta = -40 to  $+85^{\circ}C$ .

## **Function Table**

#### **Control Inputs**

| G | DIR | Operation                    |
|---|-----|------------------------------|
| L | L   | B data to A bus              |
| L | Н   | $\overline{A}$ data to B bus |
| Н | Х   | Isolation                    |
|   |     |                              |

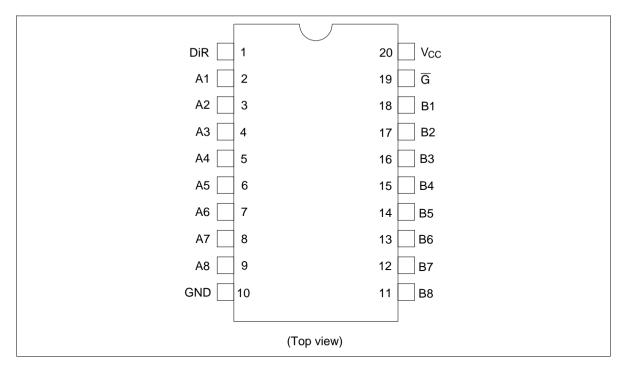
H : High level

L : Low level

X : Immaterial



## **Pin Arrangement**



## **Absolute Maximum Ratings**

| Item                     | Symbol                | Rating       | Unit |  |
|--------------------------|-----------------------|--------------|------|--|
| Supply voltage           | V <sub>cc</sub>       | -0.5 to +7.0 | V    |  |
| Input diode current      | I <sub>IК</sub>       | ±30          | mA   |  |
| Input voltage            | V <sub>IN</sub>       | -0.5 to +7.5 | V    |  |
| Output voltage           | V <sub>OUT</sub>      | -0.5 to +7.5 | V    |  |
| Off state output voltage | $V_{\text{OUT(off)}}$ | -0.5 to +5.5 | V    |  |
| Storage temperature      | Tstg                  | -65 to +150  | °C   |  |

Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

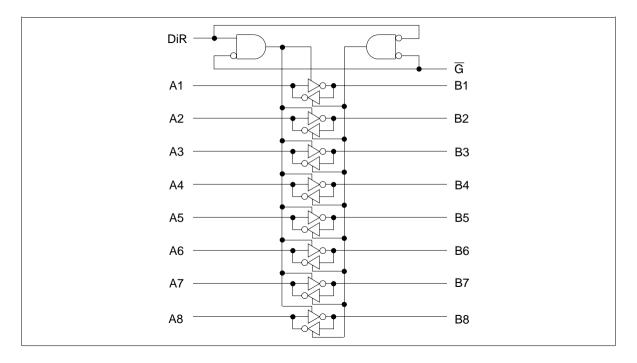
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## **Recommended Operating Conditions**

| Item                   | Symbol                          | Min | Тур | Max             | Unit |  |
|------------------------|---------------------------------|-----|-----|-----------------|------|--|
| Supply voltage         | V <sub>cc</sub>                 | 4.5 | 5.0 | 5.5             | V    |  |
| Input voltage          | V <sub>IN</sub>                 | 0   |     | V <sub>cc</sub> | V    |  |
| Ouput voltage          | V <sub>OUT</sub>                | 0   |     | V <sub>cc</sub> | V    |  |
| Operating temperature  | Topr                            | -40 | _   | 85              | °C   |  |
| Input rise/fall time*1 | t <sub>r</sub> , t <sub>f</sub> | 0   |     | 8               | ns/V |  |

Note: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.

## Logic Diagram



| Item                           | Symbol           | V <sub>cc</sub> (V) | Min  | Max  | Unit | Test Conditions  |
|--------------------------------|------------------|---------------------|------|------|------|--|
| Input voltage                  | V <sub>IH</sub>  |                     | 2.0  | —    | V    |  |
|                                | V <sub>IL</sub>  |                     |      | 0.8  | V    |  |
| Output voltage                 | V <sub>OH</sub>  | 4.5                 | 2.4  |      | V    | I <sub>он</sub> = –3 mA                                      |
|                                |                  | 4.5                 | 2.0  |      | V    | I <sub>он</sub> = –15 mA                                     |
|                                | V <sub>OL</sub>  | 4.5                 | —    | 0.5  | V    | I <sub>oL</sub> = 48 mA                                      |
|                                |                  | 4.5                 |      | 0.55 | V    | I <sub>oL</sub> = 64 mA                                      |
| Input diode voltage            | V <sub>IK</sub>  | 4.5                 | _    | -1.2 | V    | I <sub>IN</sub> = -18 mA                                     |
| Input current                  | I <sub>1</sub>   | 5.5                 | —    | -250 | μΑ   | $V_{IN} = 0 V$   |
|                                |                  | 5.5                 | _    | 100  | μΑ   | An or Bn, $V_{IN} = 5.5 V$                                   |
|                                |                  | 5.5                 | _    | 1.0  | μΑ   | DiR or $\overline{G}$ , V <sub>IN</sub> = 5.5 V              |
|                                |                  | 5.5                 | —    | 100  | μΑ   | DiR or $\overline{G}$ , V <sub>IN</sub> = 7 V                |
| Output short circuit current*1 | I <sub>os</sub>  | 5.5                 | -100 | -225 | mA   | $V_{\rm o}$ = 0 V, $V_{\rm IN}$ = 0 or 5.5 V                 |
| Off state output current       | I <sub>OZH</sub> | 5.5                 | _    | -100 | μΑ   | V <sub>0</sub> = 2.7 V                                       |
|                                | I <sub>OZL</sub> | 5.5                 | —    | -250 | μΑ   | V <sub>0</sub> = 0.5 V                                       |
| Supply current                 | I <sub>CCL</sub> | 5.5                 | _    | 29.5 | mA   | $V_{IN} = 0 \text{ or } 5.5 \text{ V}$<br>All outputs is "L" |
|                                | I <sub>CCH</sub> | 5.5                 | _    | 2.5  | mA   | $V_{IN} = 0 \text{ or } 5.5 \text{ V}$<br>All outputs is "H" |
|                                | I <sub>ccz</sub> | 5.5                 | _    | 4.5  | mA   | $V_{IN} = 0 \text{ or } 5.5 \text{ V}$<br>All outputs is "Z" |
|                                | I*2              | 5.5                 | _    | 1.5  | mA   | $V_{IN} = 3.4 \text{ or } 0.5 \text{ V}$                     |

## **Electrical Characteristics** (Ta = -40 to $+85^{\circ}$ C)

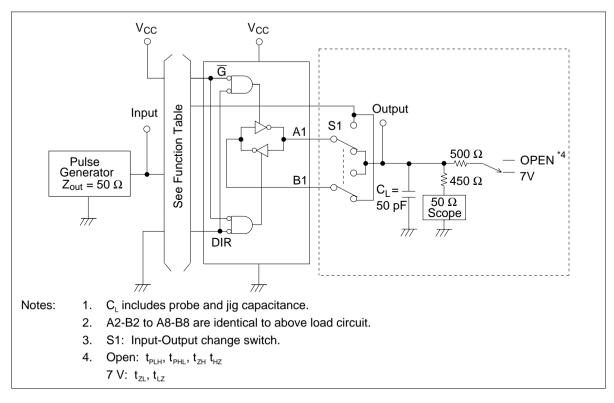
Notes: 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

2. When input by the TTL level, it shows  $\rm I_{\rm cc}$  increase at per one input pin.

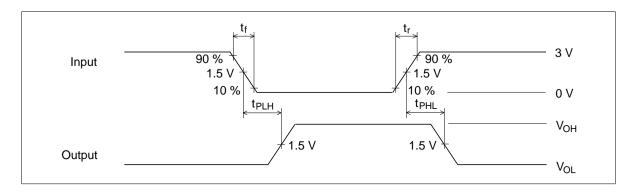
# Switching Characteristics ( $C_L = 50 \text{ pF}$ )

|                        |                  | Ta = 25°C<br>V <sub>cc</sub> = 5.0 V |     | Ta = -40 to +85°C<br>V <sub>cc</sub> = 5.0 V ±10% |      |      |                                   |  |
|------------------------|------------------|--------------------------------------|-----|---|------|------|-----------------------------------|--|
| Item                   | Symbol           | Min                                  | Max | Min   | Max  | Unit | Test Conditions                   |  |
| Propagation delay time | t <sub>PLH</sub> | 3.0                                  | 6.0 | 3.0   | 7.0  | ns   | An to Bn                          |  |
|                        | t <sub>PHL</sub> | 3.0                                  | 6.0 | 3.0   | 7.0  | _    |                                   |  |
|                        | t <sub>PLH</sub> | 3.0                                  | 6.0 | 3.0   | 7.0  | ns   | Bn to An                          |  |
|                        | t <sub>PHL</sub> | 3.0                                  | 6.0 | 3.0   | 7.0  | _    |                                   |  |
| Output enable time     | t <sub>zH</sub>  | 3.0                                  | 9.0 | 3.0   | 11.0 | ns   | G to Bn                           |  |
|                        | t <sub>zL</sub>  | 3.0                                  | 9.0 | 3.0   | 11.0 |      |                                   |  |
|                        | t <sub>zH</sub>  | 3.0                                  | 9.0 | 3.0   | 11.0 | ns   | G to An                           |  |
|                        | t <sub>zL</sub>  | 3.0                                  | 9.0 | 3.0   | 11.0 |      |                                   |  |
| Output disable time    | t <sub>HZ</sub>  | 3.0                                  | 8.0 | 3.0   | 10.0 | ns   | G to Bn                           |  |
|                        | t <sub>LZ</sub>  | 3.0                                  | 8.0 | 3.0   | 10.0 |      |                                   |  |
|                        | t <sub>HZ</sub>  | 3.0                                  | 8.0 | 3.0   | 10.0 | ns   | G to An                           |  |
|                        | t <sub>LZ</sub>  | 3.0                                  | 8.0 | 3.0   | 10.0 | _    |                                   |  |
| Input capacitance      | CIN              | 3.0 (Тур)                            |     | _   |      | pF   | $V_{IN} = V_{CC} \text{ or } GND$ |  |
| Output capacitance     | C <sub>I/O</sub> | 15.0 (Typ)                           |     | _   |      | pF   | $V_{I/O} = V_{CC}$ or GND         |  |

#### **Test Circuit**

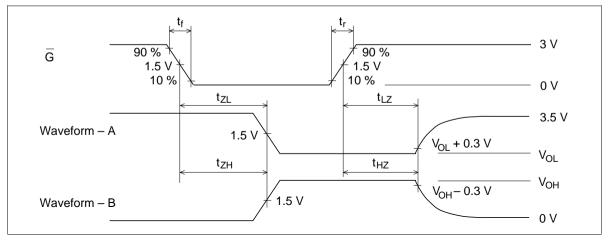


#### Waveforms-1



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#### Waveforms-2



Notes: 1.  $t_r = 2.5 \text{ ns}, t_f = 2.5 \text{ ns}$ 

- 2. Input waveforms: PRR = 1 MHz, duty cycle 50%
- 3. Waveform-A shows input conditions such that the output is "L" level when enable by the output control.
- 4. Waveform-B shows input conditions such that the output is "H" level when enable by the output control.

## Package Dimensions

Unit: mm

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